

Silicon NPN Phototransistor

Version 1.3

SFH 309



Features:

- **Spectral range of sensitivity:** (typ) 380 ... 1150 nm
- **Package:** 3mm Radial (T 1), Epoxy
- **Special:** High photosensitivity
- High linearity
- Available in groups

Applications

- Photointerrupters
- Industrial electronics
- For control and drive circuits

Ordering Information

Type:	Photocurrent I_{PCE} [μ A] $\lambda = 950 \text{ nm}$, $E_e = 0.5 \text{ mW/cm}^2$, $V_{CE} = 5 \text{ V}$	Ordering Code
SFH 309	400 ... 5000	Q62702P0859
SFH 309-3/4	630 ... 2000	Q62702P3592
SFH 309-4	1000 ... 2000	Q62702P0998
SFH 309-4/5	1000 ... 3200	Q62702P3593
SFH 309-5	1600 ... 3200	Q62702P0999
SFH 309-5/6	1600 ... 5000	Q62702P3594

Note: Only one bin within one packing unit (variation less than 2:1)

Maximum Ratings ($T_A = 25\text{ °C}$)

Parameter	Symbol	Values	Unit
Operating and storage temperature range	$T_{op}; T_{stg}$	-40 ... 100	°C
Collector-emitter voltage	V_{CE}	35	V
Collector current	I_C	15	mA
Collector surge current ($\tau < 10\ \mu\text{s}$)	I_{CS}	75	mA
Total Power dissipation	P_{tot}	165	mW
Thermal resistance	R_{thJA}	450	K / W
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V_{ESD}	2000	V

Characteristics ($T_A = 25\text{ °C}$)

Parameter		Symbol	Values	Unit
Wavelength of max. sensitivity	(typ)	$\lambda_{S\ max}$	860	nm
Spectral range of sensitivity	(typ)	$\lambda_{10\%}$	(typ) 380 ... 1150	nm
Radiant sensitive area ($\varnothing 220\ \mu\text{m}$)	(typ)	A	0.038	mm ²
Dimensions of chip area	(typ)	L x W	(typ) 0.45 x 0.45	mm x mm
Distance chip front to case surface	(min ... max)	H	(min ... max) 2.4 ... 2.8	mm
Half angle	(typ)	φ	± 12	°
Capacitance ($V_{CE} = 0\ \text{V}$, $f = 1\ \text{MHz}$, $E = 0$)	(typ)	C_{CE}	5	pF
Dark current ($V_{CE} = 20\ \text{V}$, $E = 0$)	(typ (max))	I_{CE0}	1 (≤ 50)	nA

Grouping ($T_A = 25\text{ °C}$, $\lambda = 950\text{ nm}$)

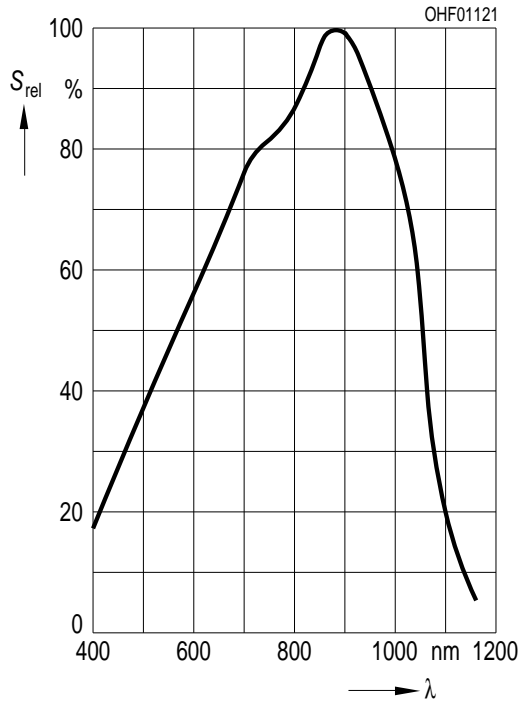
Group	Min Photocurrent $E_e = 0.5\text{ mW/cm}^2$, $V_{CE} = 5\text{ V}$ $I_{PCE, min}\text{ [}\mu\text{A]}$	Max Photocurrent $E_e = 0.5\text{ mW/cm}^2$, $V_{CE} = 5\text{ V}$ $I_{PCE, max}\text{ [}\mu\text{A]}$	Typ Photocurrent $E_V = 1000\text{ lx, Std. Light A, } V_{CE} = 5\text{ V}$ $I_{PCE}\text{ [}\mu\text{A]}$	Rise and fall time $I_C = 1\text{ mA, } V_{CC} = 5\text{ V, } R_L = 1\text{ k}\Omega$ $t_r, t_f\text{ [}\mu\text{s]}$
-2	400	800	1500	5
-3	630	1250	2800	6
-4	1000	2000	4500	7
-5	1600	3200	7200	8
-6	2500	5000	11200	9

Group	Collector-emitter saturation voltage $I_C = I_{PCEmin} \times 0.3, E_e = 0.5\text{ mW/cm}^2$ $V_{CEsat}\text{ [mV]}$
-2	200
-3	200
-4	200
-5	200
-6	200

Note.: I_{PCEmin} is the min. photocurrent of the specified group.

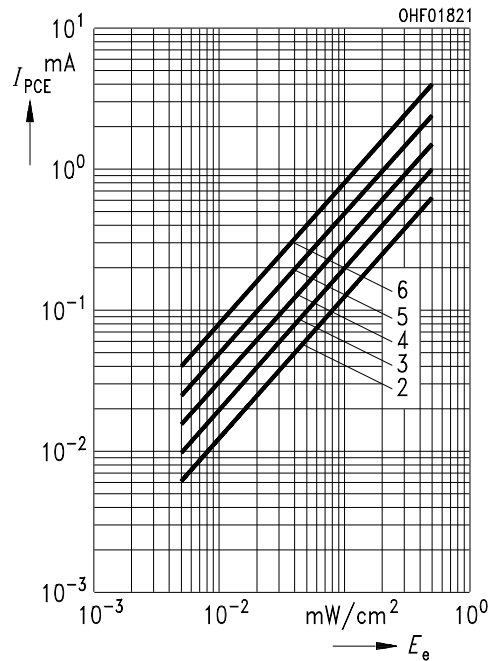
Relative Spectral Sensitivity ^{1) page 9}

$S_{rel} = f(\lambda)$



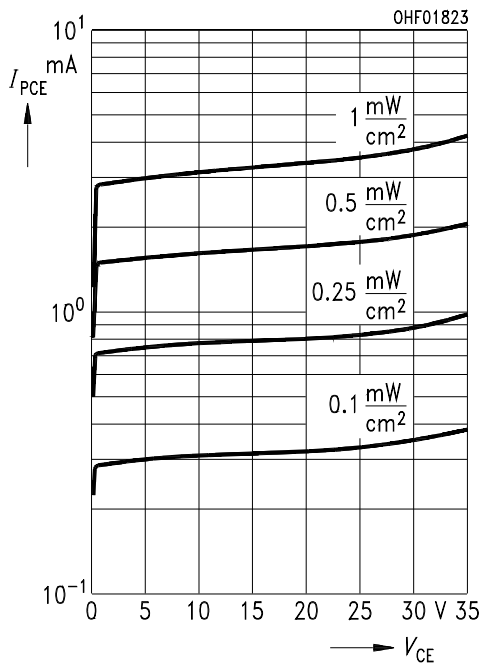
Photocurrent ^{1) page 9}

$I_{PCE} = f(E_e), V_{CE} = 5 V$



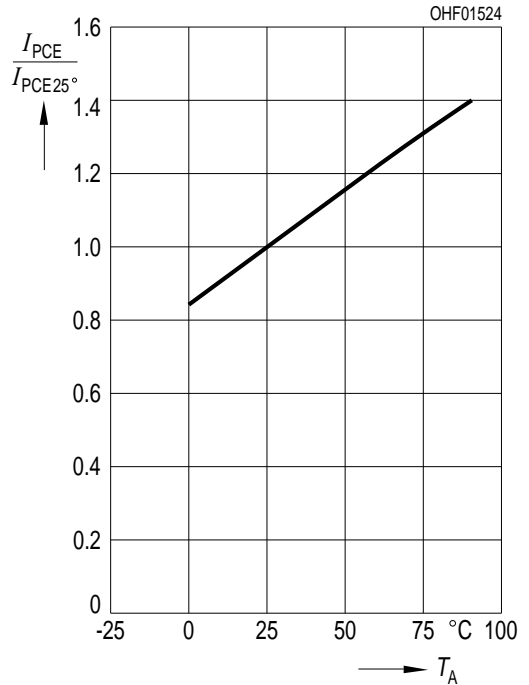
Photocurrent ^{1) page 9}

$I_{PCE} = f(V_{CE}), E_e = \text{Parameter}$



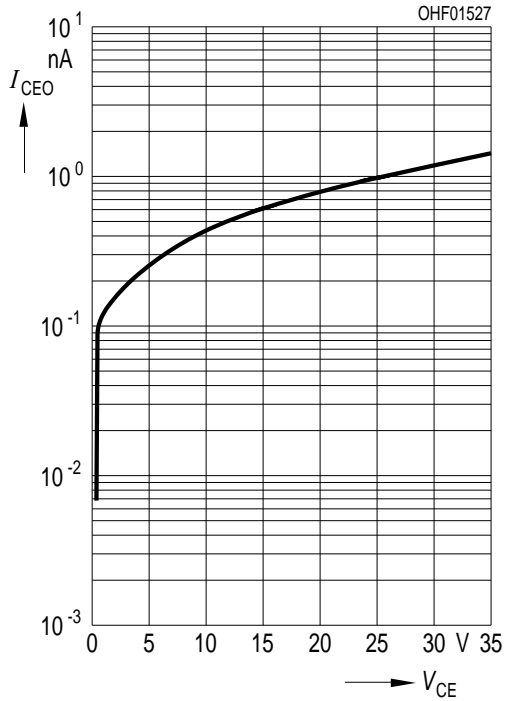
Photocurrent ^{1) page 9}

$I_{PCE} / I_{PCE}(25^\circ C) = f(T_A), V_{CE} = 5 V$



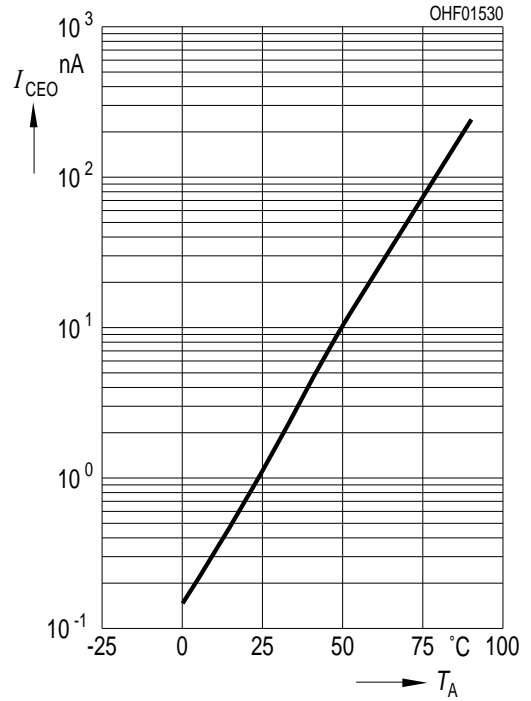
Dark Current ^{1) page 9}

$I_{CE0} = f(V_{CE}), E = 0$



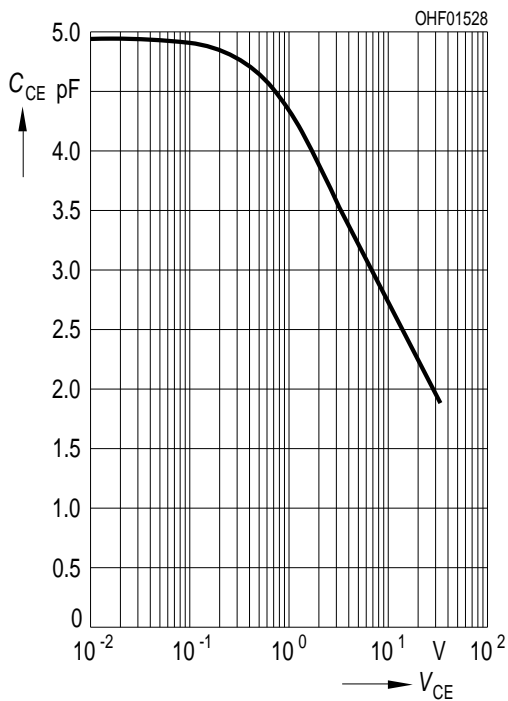
Dark Current ^{1) page 9}

$I_{CE0} = f(T_A), V_{CE} = 20 \text{ V}, E = 0$



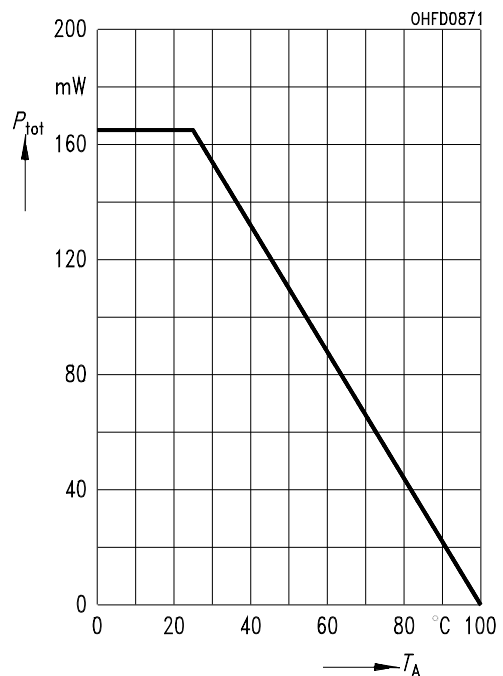
Collector-Emitter Capacitance ^{1) page 9}

$C_{CE} = f(V_{CE}), f = 1 \text{ MHz}, E = 0$



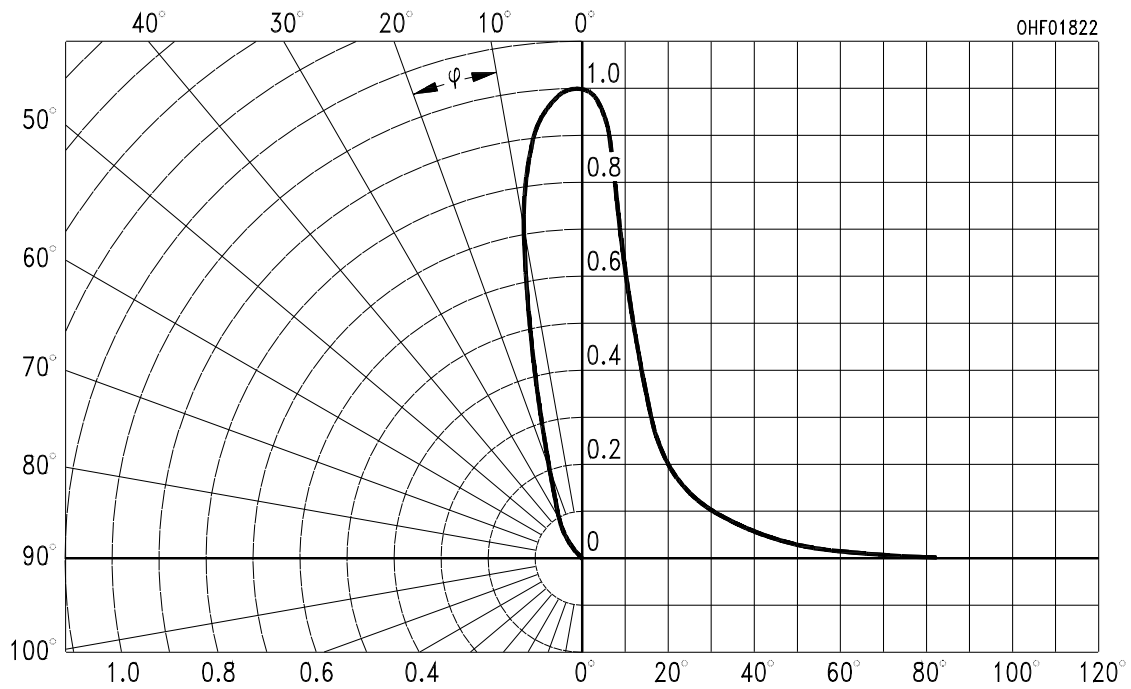
Power Consumption

$P_{tot} = f(T_A)$

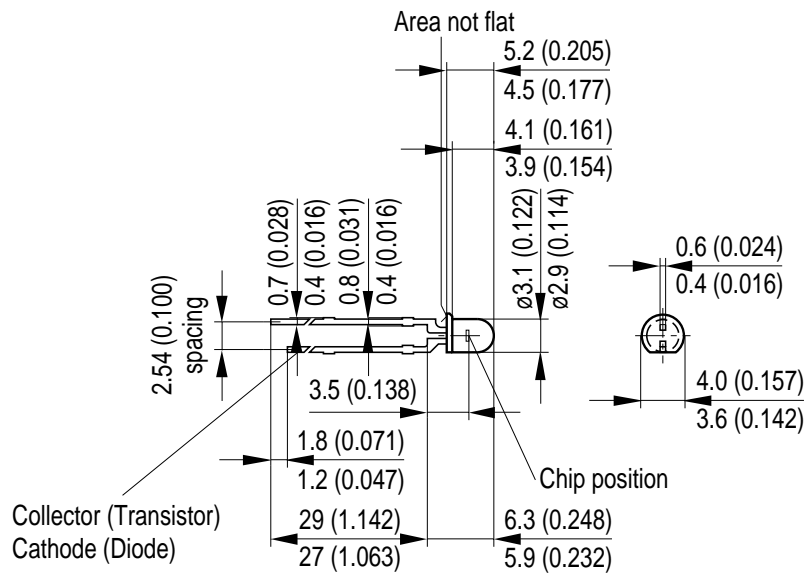


Directional Characteristics ^{1) page 9}

$S_{rel} = f(\phi)$



Package Outline



Dimensions in mm (inch).

Package

3mm Radial (T 1), Epoxy

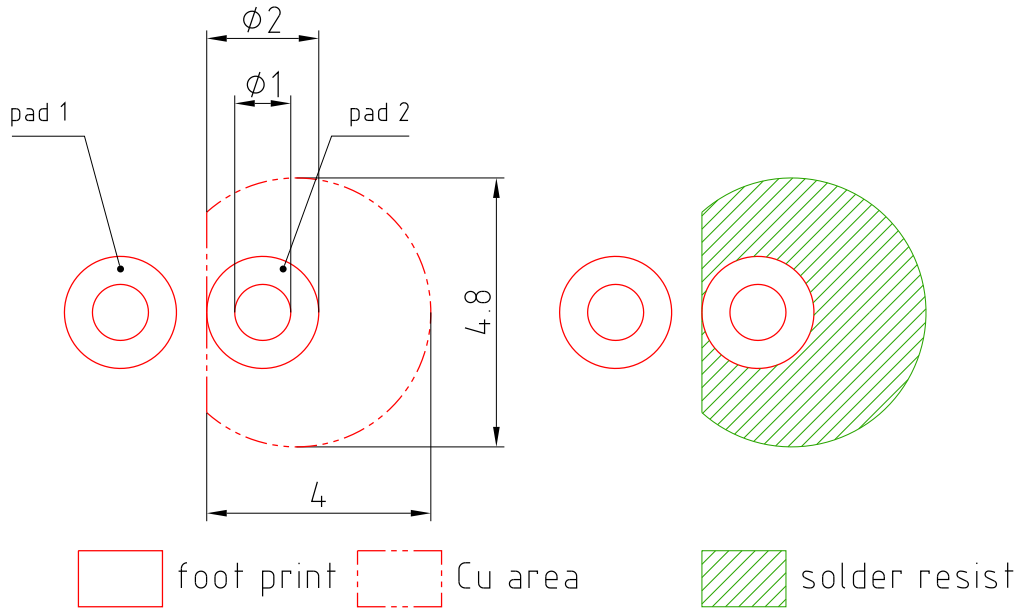
Approximate Weight:

0.2 g

Note

Packing information is available on the internet (online product catalog).

Recommended Solder Pad



E062.3010.188-01

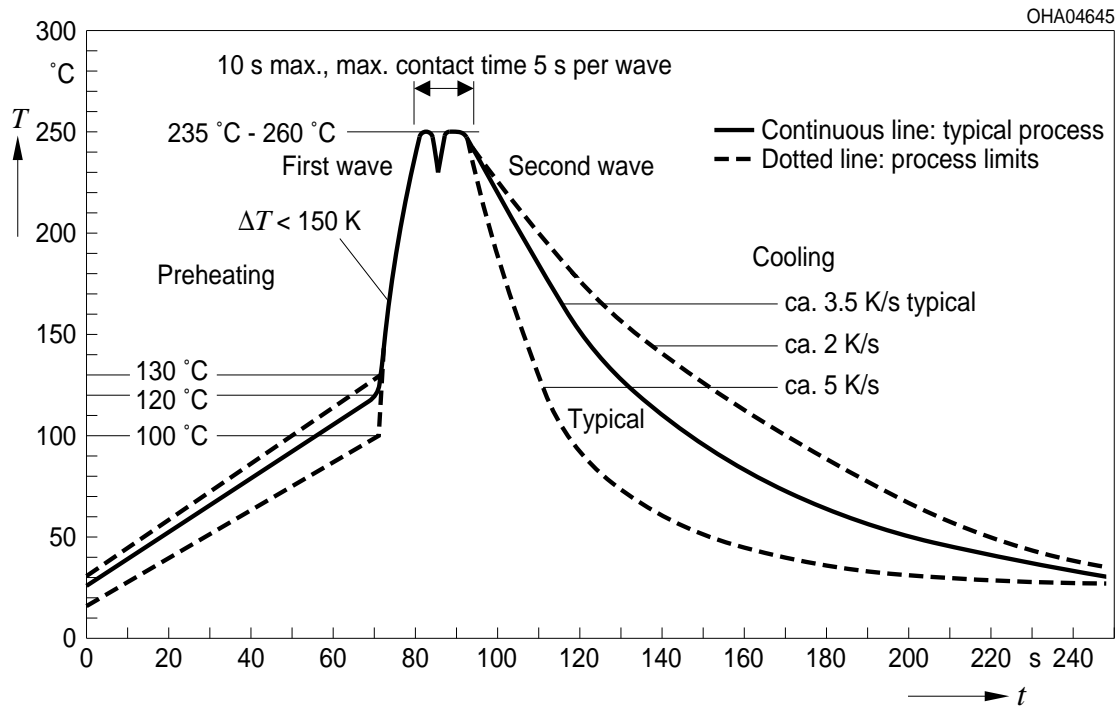
Dimensions in mm.

Note:

pad 1: emitter

TTW Soldering

IEC-61760-1 TTW

**Disclaimer**

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

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**) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.

Glossary

- ¹⁾ **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

Published by OSRAM Opto Semiconductors GmbH
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